

FX50SMJ-06

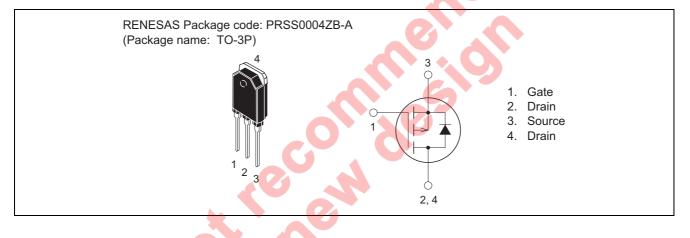
High-Speed Switching Use Pch Power MOS FET

> REJ03G1453-0200 (Previous: MEJ02G0278-0101) Rev.2.00 Aug 07, 2006

Features

- Drive voltage : 4 V
- V_{DSS} : -60 V
- $r_{DS(ON) (max)}$: 18.9 m Ω
- I_D: -50 A
- Integrated Fast Recovery Diode (TYP.): 70 ns

Outline



Applications

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

Maximum Ratings

	•			$(\mathrm{Tc} = 25^{\circ}\mathrm{C})$
Parameter	Symbol	Ratings	Unit	Conditions
Drain-source voltage	V _{DSS}	-60	V	$V_{GS} = 0 V$
Gate-source voltage	V _{GSS}	±20	V	$V_{DS} = 0 V$
Drain current	I _D	-50	А	
Drain current (Pulsed)	I _{DM}	-200	А	
Avalanche drain current (Pulsed)	I _{DA}	-50	А	L = 50 μH
Source current	I _S	-50	А	
Source current (Pulsed)	I _{SM}	-200	А	
Maximum power dissipation	PD	150	W	
Channel temperature	Tch	– 55 to +150	°C	
Storage temperature	Tstg	- 55 to +150	°C	
Mass	_	4.8	g	Typical value

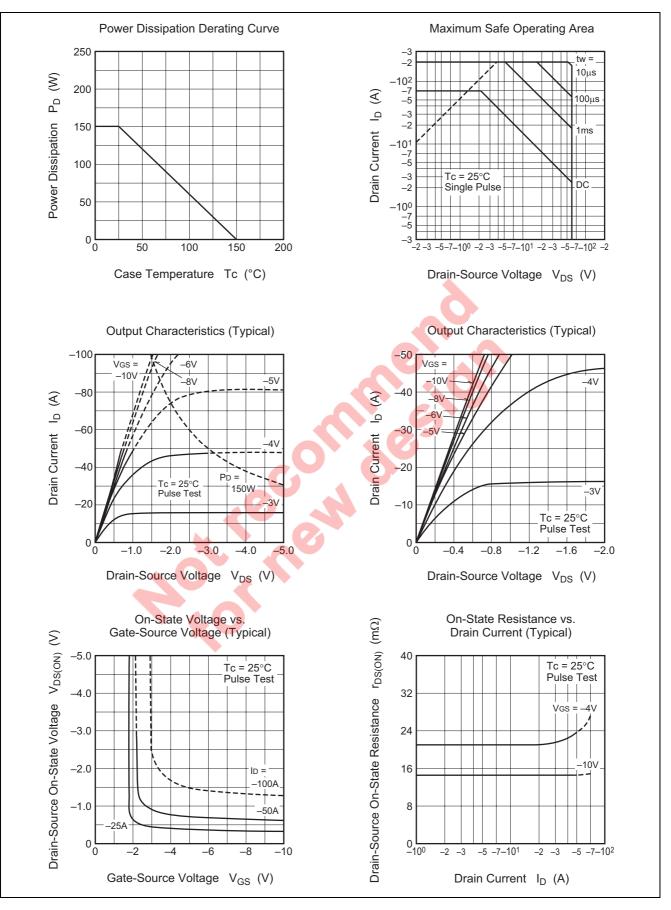


Electrical Characteristics

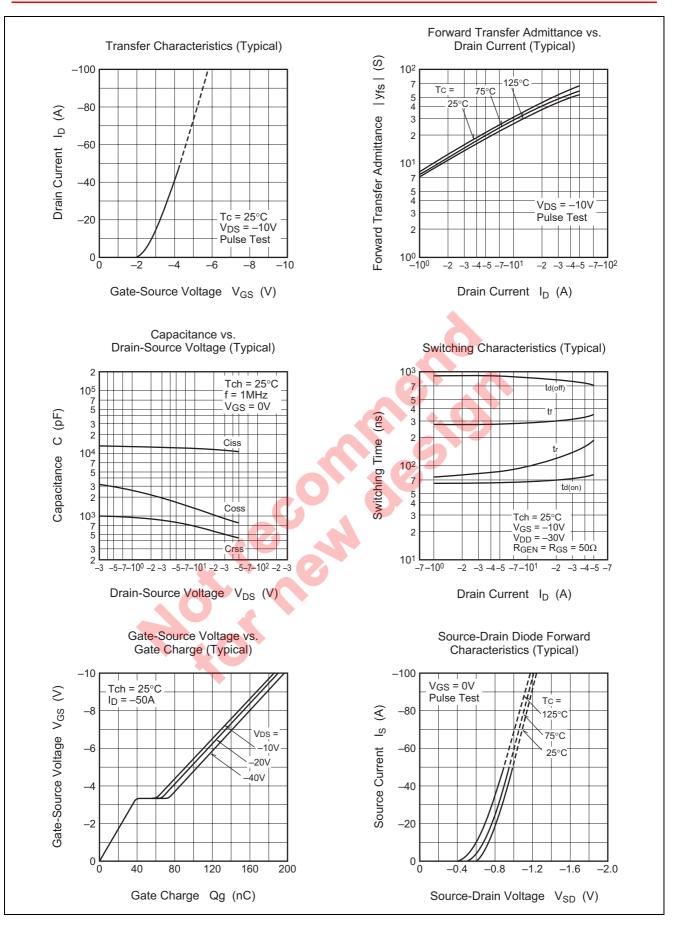
	$(Tch = 25^{\circ}C)$							
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions		
Drain-source breakdown voltage	V _{(BR)DSS}	-60	—	—	V	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$		
Gate-source leakage current	I _{GSS}	—	—	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$		
Drain-source leakage current	I _{DSS}	—	—	0.1	mA	$V_{DS} = -60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		
Gate-source threshold voltage	V _{GS(th)}	-1.3	-1.8	-2.3	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$		
Drain-source on-state resistance	r _{DS(ON)}	—	15.0	18.9	mΩ	$I_D = -25 \text{ A}, V_{GS} = -10 \text{ V}$		
Drain-source on-state resistance	r _{DS(ON)}	—	23	32	mΩ	$I_D = -25 \text{ A}, V_{GS} = -4 \text{ V}$		
Drain-source on-state voltage	V _{DS(ON)}	—	-0.38	-0.47	V	$I_D = -25 \text{ A}, V_{GS} = -10 \text{ V}$		
Forward transfer admittance	y _{fs}	—	49.1	—	S	$I_D = -25 \text{ A}, V_{DS} = -10 \text{ V}$		
Input capacitance	Ciss	—	11610	—	pF	$V_{DS} = -10 V$, $V_{GS} = 0 V$,		
Output capacitance	Coss	—	1355	—	pF	f = 1MHz		
Reverse transfer capacitance	Crss	—	687	—	pF			
Turn-on delay time	t _{d(on)}	—	73	—	ns	$V_{DD} = -30 \text{ V}, \text{ I}_{D} = -25 \text{ A},$		
Rise time	tr	—	137	—	ns	$V_{GS} = -10 V$,		
Turn-off delay time	t _{d(off)}	—	822	—	ns	$R_{GEN} = R_{GS} = 50 \ \Omega$		
Fall time	t _f	—	320	—	ns			
Source-drain voltage	V _{SD}	—	-1.0	-1.5	V	$I_{S} = -25 \text{ A}, V_{GS} = 0 \text{ V}$		
Thermal resistance	R _{th(ch-c)}	—	—	0.83	°C/W	Channel to case		
Reverse recovery time	t _{rr}	_	70		ns	Is = –50 A, d _{is} /d _t = 100 A/μs		



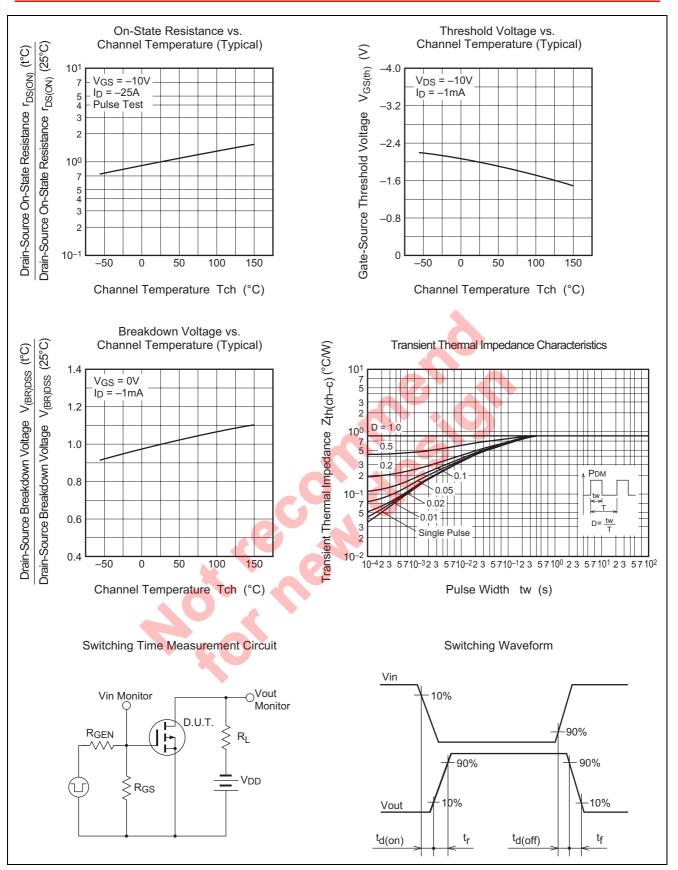
Performance Curves



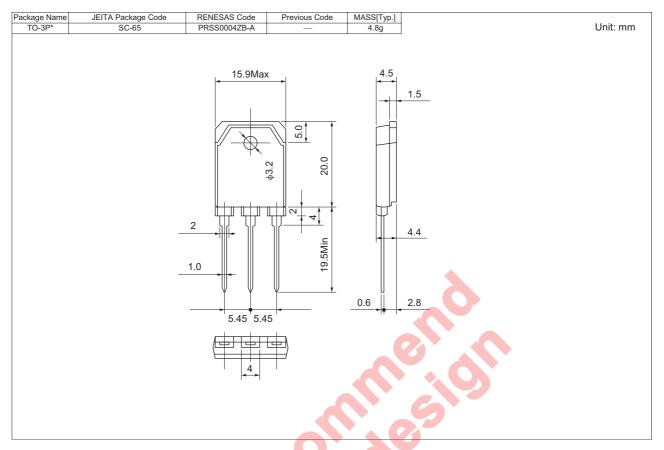








Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Static electricity prevention bag	20	Type name	FX50SMJ-06
Lead form	Plastic Magazine (Tube)	30	Type name – Lead forming code	FX50SMJ-06-A8

Note : Please confirm the specification about the shipping in detail.

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